

TO9

High Power Multi-Mode SemiNex Lasers 2.5 Watts CW 1470 and 1550 nm standard Custom Wavelengths Available

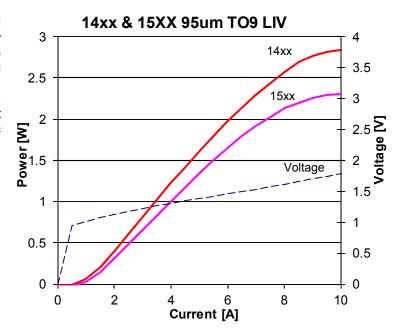
Features

- High output power
- High dynamic power range
- High efficiency
- Standard Low Cost Package

Applications

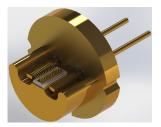
- · Medical laser equipment
- LIDAR
- Free Space Optical Communication
- DPSS pump lasers
- Military / Aerospace

SemiNex delivers the highest available power at infrared wavelengths between 13xx and 17xx nm. When necessary we will further optimize the design of our InP laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements



All statements, technical information and recommendation related to the product herein are based upon information believed to be reliable or accurate. However, the accuracy or completeness hereof is not guaranteed, and no responsibility is assumed for any inaccuracies. The user assumes all risks and liability whatsoever in connection with the use of a product or its application. SemiNex Incorporated reserves the right to change at any time without notice, the design, specification, deduction, fit or form of its described herein, including withdrawal at any time of a product offered for sale herein. SemiNex Incorporated makes no representations that the products herein are free from any intellectual property claims of others. Please contact SemiNex Incorporated for more information. © 2012 Copyright SemiNex Incorporated. All rights reserved.

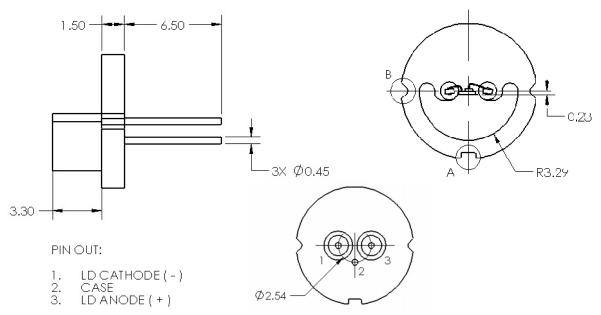






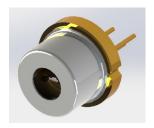
	Symbol	TO9-110	TO9-102	TO9-118	TO9-116	Units
Optical						
Center Wavelength	λ_{c}	1455	1475	1540	1550	watts
Output power (CW)	P_{o}	2.5	2.5	2	2	nm
Emitter Width	W	95	95	95	95	μm
Emitter Height	Н	1	1	1	1	μm
Spectral Width	Δλ	10	10	10	10	nm 3dB
Slope Efficiency	η_{o}	0.4	0.4	0.3	0.3	W/A
Fast Axis Divergence	θ_Χ	28	28	28	28	deg FWHM
Slow Axis Divergence	θ_Υ	9	9	9	9	deg FWHM
Electrical						
Power conversion Efficiency	η	0.2	0.2	0.16	0.16	
Threshold Current	I_{th}	0.5	0.5	0.5	0.5	Α
Operating Current	I_{op}	8	8	8	8	Α
Operating Voltage	V_{op}	1.6	1.6	1.6	1.6	V
Series Resistance	R_s	0.05	0.05	0.05	0.05	ohm

Specified values are rated at constant heat sink temperature of 20°C



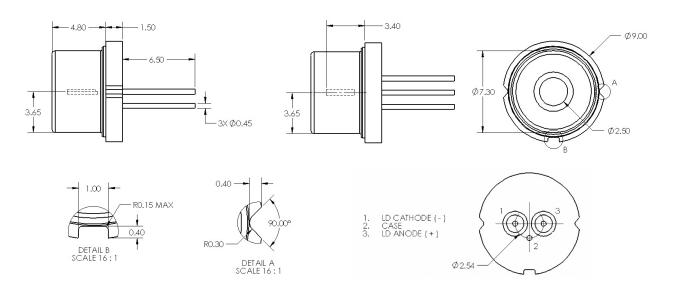
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	Symbol	TO9-125	TO9-126	TO9-104	TO9-107	Units
Optical						
Center Wavelength	λα	1490	1500	1575	1585	nm
Output power (CW)	P∘	2	2	1.7	1.7	watts
Emitter Width	W	95	95	95	95	μm
Emitter Height	Н	1	1	1	1	μm
Spectral Width	Δλ	10	10	10	10	nm 3dB
Slope Efficiency	ηο	0.36	0.36	0.3	0.3	W/A
Fast Axis Divergence	θ_Χ	28	28	28	28	deg FWHM
Slow Axis Divergence	θ_Υ	9	9	9	9	deg FWHM
Electrical						
Power conversion Efficiency	η	0.2	0.2	0.17	0.17	
Threshold Current	l th	0.5	0.5	0.5	0.5	Α
Operating Current	l op	7	7	7	7	Α
Operating Voltage	Vop	1.4	1.4	1.4	1.4	V
Series Resistance	Rs	0.05	0.05	0.05	0.05	ohm
Mechanical						
Weight		1.9	1.9	1.9	1.9	g
Operating Temperature		10 to 30	10 to 30	10 to 30	10 to 30	°C
Storage Temperature		-20 to 80	-20 to 80	-20 to 80	-20 to 80	°C



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